WIDEBAND, HIGH GAIN, LOW NOISE

Monolithic Amplifier PMA3-34GLN+

50Ω 10 to 30 GHz

THE BIG DEAL

- Wideband, 10 to 30 GHz
- Usable down to 9 GHz
- High Gain, 25.5 dB typ. at 20 GHz
- Low NF, 1.6 dB typ. at 20 GHz
- P1dB, +10 dBm typ. at 20 GHz
- OIP3, +22 dBm typ. at 20 GHz
- Built-in Bias Tee and DC Blocks
- Patent Pending



Generic photo used for illustration purposes only

CASE STYLE: DQ1225

+RoHS Compliant
The +Suffix identifies RoHS Compliance.
See our website for methodologies and qualifications

APPLICATIONS

- 5G
- Fixed Satellite
- Mobile

PRODUCT OVERVIEW

The PMA3-34GLN+ is a PHEMT based wideband, low noise MMIC amplifier with a unique combination of high gain and low noise figure over a very broad bandwidth making it ideal for using as the first stage driver amplifier of receiver applications. This design operates on a single 4V supply, is matched to 50 Ohm and comes in a tiny plastic package (3 x 3 x 0.89mm), accommodating dense circuit board layouts.

KEY FEATURES

Feature	Advantages
Low noise, 1.6 dB at 20 GHz	Enables lower system noise figure performance
High Gain, 25.5 dB at 20 GHz	Enables signal amplification without the need for multiple gain stage, minimizing the effect of subsequent stages on noise figure
Built-in Bias Tee & DC Blocks	Minimizes the external component count & PC board space, making it less expensive and user friendly for system designers
3 x 3mm 12-lead MCLP package	Tiny footprint saves space in dense layouts while providing low inductance, repeatable transitions, and excellent thermal contact to the PCB

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PMA3-34GLN+
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ELECTRICAL SPECIFICATIONS[1] AT +25°C, Vs = +4V AND R1=18Ω, UNLESS NOTED OTHERWISE

Parameter	Condition (GHz)	Vs= +4 V			Units
		Min.	Typ.	Max.	
Frequency Range	—	10		30	GHz
Noise Figure	10 15 20 30	— — — —	1.9 1.8 1.6 2.4	— — — —	dB
Gain	10 15 20 30	22.5 24.7 22.2 —	25.3 27.9 25.5 18.2	29.2 31.5 31.1 —	dB
Input Return Loss	10 15 20 30		13 13 21 8		dB
Output Return Loss	10 15 20 30		12 10 10 9		dB
Output Power @ 1 dB compression	10 15 20 30		+8.5 +9.5 +10 +11		dBm
Output IP3	10 15 20 30		+18.6 +22.1 +22 +23.4		dBm
Supply Voltage (V_S)		+3.75	+4.0	+4.25	V
Device Operating Current (I_{DD})			68	112	mA
Device Current Variation vs. Temperature[2]			-50		µA/°C
Device Current Variation vs. Voltage			0.02		mA/mV
Thermal Resistance, junction-to-ground lead			106		°C/W

1. Measured on Mini-Circuits Characterization test board TB-PMA3-34GLN+ with thru-line loss being deducted. See Characterization Test Circuit (Fig. 1)
2. Device Current Variation vs. Temperature = (Current at 85°C - Current at -45°C)/130°C

ABSOLUTE MAXIMUM RATINGS[3]

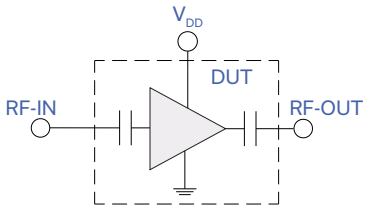
Parameter	Ratings
Operating Temperature (ground lead)	-40°C to +85°C
Storage Temperature	-65°C to +150°C
Junction Temperature	+146°C
Total Power Dissipation	0.65W
Input Power (CW), Vs= +4 V	+23 dBm (5 minutes max.) +13 dBm (continuous)
DC Voltage at Port 2 & 8	+2 V
DC Voltage (Vs)	+6 V

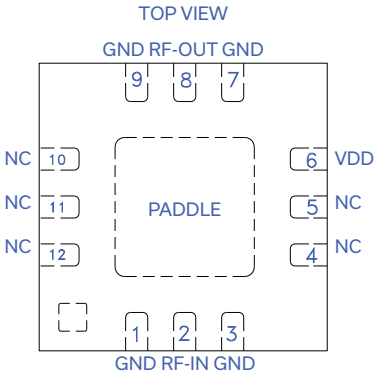
3.Permanent damage may occur if any of these limits are exceeded. Electrical maximum ratings are not intended for continuous normal operation.

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SIMPLIFIED SCHEMATIC AND PAD DESCRIPTION





Function	Pad Number	Description (Fig. 1)
RF-IN	2	RF Input Pad. Connects to RF input
RF-OUT	8	RF Output Pad. Connects to RF output
V_{DD}	6	DC Power Supply Pad. Connects to Voltage Source Vs via R1
Ground	1,3,7,9 & Paddle	Connects to ground
No Connection	4,5,10,11& 12	Not used internally. Connected to ground on test board

RECOMMENDED APPLICATION AND CHARACTERIZATION TEST CIRCUIT

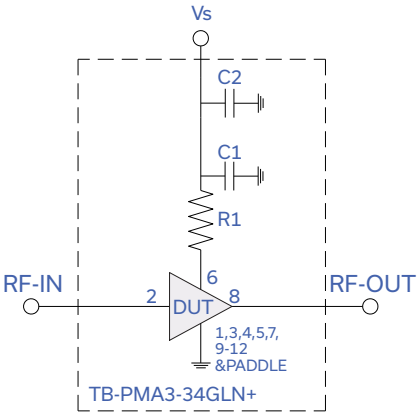
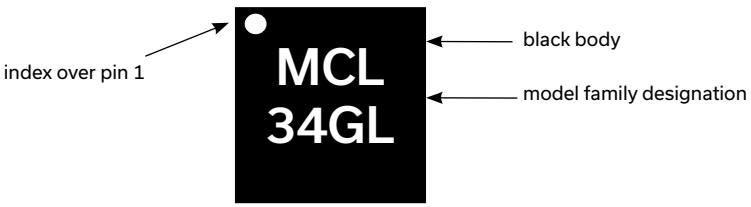


Fig 1. Application and Characterization Circuit
Note: This block diagram is used for characterization. (DUT is soldered on Mini-Circuits Characterization test board TB-PMA3-34GLN+) Gain, Return loss, Output power at 1dB compression (P1 dB), output IP3 (OIP3) and noise figure measured using Agilent's N5245A microwave network analyzer.

Conditions:
1. Gain and Return loss: Pin= -25dBm
2. Output IP3 (OIP3): Two tones, spaced 1 MHz apart, -5dBm/tone at output.

Component	Size	Value	Part Number	Manufacturer
R1	0402	18 Ohm	RK73G1ETTP18ROF	KOA
C1	0402	5 pF	GJM1555C1H5R0CB01D	Murata
C2	0402	0.1 uF	GRM155R71C104KA88D	Murata

PRODUCT MARKING



Marking may contain other features or characters for internal lot control

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ADDITIONAL DETAILED TECHNICAL INFORMATION IS AVAILABLE ON OUR DASH BOARD. TO ACCESS CLICK HERE

Performance Data	Data Table graphs, s-parameter data set (.zip file)
Case Style	DQ1225 Plastic package, exposed paddle, lead finish: Matte Tin
Tape & Reel **Standard quantities available on reel**	F66 7" reels with 20, 50, 100, 200, 500, 1K, 2K or 3K devices
Suggested Layout for PCB Design	PL-674
Evaluation Board	TB-PMA3-34GLN+ (Without connectors) TB-PMA3-34GLNC+ (With connectors)
Environmental Ratings	ENV08T1

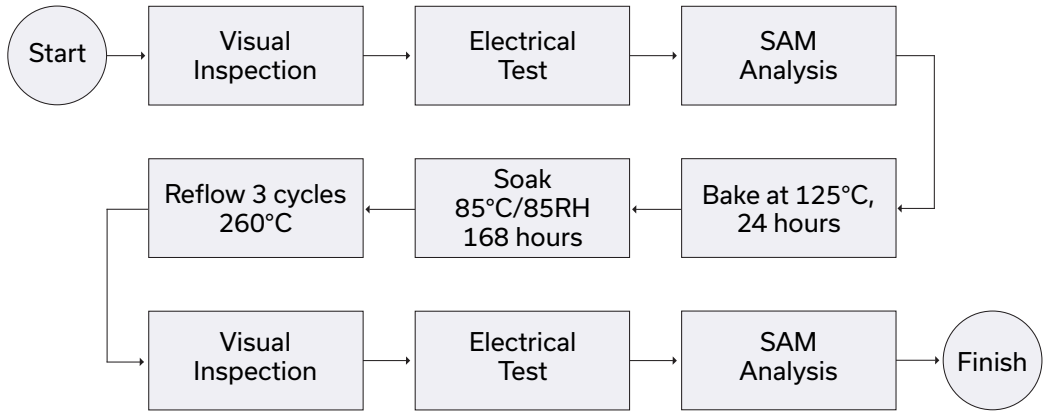
ESD RATING

Human Body Model (HBM): Class 1A (250 to <500V) in accordance with ANSI/ESD STM 5.1 - 2001

MSL RATING

Moisture Sensitivity: MSL1 in accordance with IPC/JEDEC J-STD-020D

MSL TEST FLOW CHART



NOTES

A. Performance and quality attributes and conditions not expressly stated in this specification document are intended to be excluded and do not form a part of this specification document.
B. Electrical specifications and performance data contained in this specification document are based on Mini-Circuit's applicable established test performance criteria and measurement instructions.
C. The parts covered by this specification document are subject to Mini-Circuits standard limited warranty and terms and conditions (collectively, "Standard Terms"); Purchasers of this part are entitled to the rights and benefits contained therein. For a full statement of the standard. Terms and the exclusive rights and remedies thereunder, please visit Mini-Circuits' website at www.minicircuits.com/MCLStore/terms.jsp